



正基科技股份有限公司

SPECIFICATION

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	APPROVED	CHECKED	PREPARED	DCC ISSUE
NAME				



AMPAK

AP6493

WiFi 11b/g/n+ Bluetooth 4.0 + NFC SIP Module Spec Sheet



Revision History

Date	Revision Content	Revised By	Version
2012/10/05	- Preliminary	Joe	1.0
2012/10/26	- Modify pin define	Joe	1.1
2012/10/30	- Modify pin define	Joe	1.2
2013/01/18	- Specification modify	Joe	1.3
		- 63	17
		9,7/	
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1. Introduction

AMPAK Technology would like to announce a low-cost and low-power consumption module, which has all of the WiFi, Bluetooth, and NFC functionalities. The highly integrated AP6493 module makes the possibilities of web browsing, VoIP, Bluetooth headsets, and other applications. With seamless roaming capabilities and advanced security, AP6493 can also interact with different vendors' 802.11b/g/n Access Points in the wireless LAN.

The wireless module complies with IEEE 802.11 b/g/n standard and it can achieve up to a speed of 72.2Mbps with single stream in 802.11n draft, 54Mbps as specified in IEEE 802.11g, or 11Mbps for IEEE 802.11b to connect to the wireless LAN. The integrated module provides SDIO (4bit/1bit) interface for WiFi, UART / PCM interface for Bluetooth and UART / PCM interface.

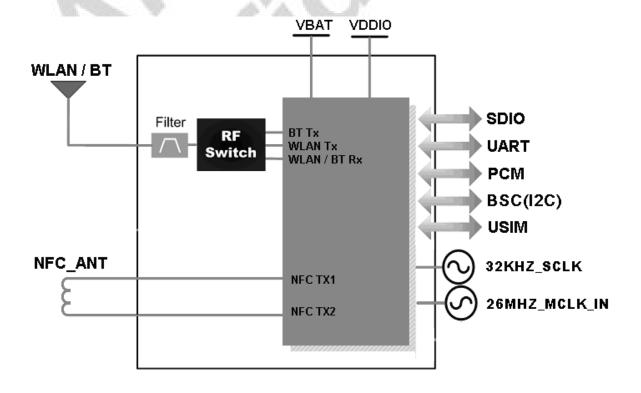
This compact module is a total solution for a combination of WiFi + BT + NFC technologies. The module is specifically developed for Smart phones and Portable devices.



2. Features

- 802.11b/g/n single-band radio
- Bluetooth V4.0(HS) with integrated Class 1 PA and Low Energy (BLE) support
- Concurrent Bluetooth and WLAN operation
- Simultaneous BT/WLAN receive with single antenna
- WLAN host interface options:
 - SDIO v2.0 up to 50 MHz clock rate
- BT host digital interface:
 - UART (up to 4 Mbps)
- IEEE Co-existence technologies are integrated die solution
- ECI enhanced coexistence support, ability to coordinate BT SCO transmissions around WLAN receives
- NFC Support for the ISO/IEC 18092, ISO/IEC 21481, ISO/IEC 14443 Types A, B and B', Japanese Industrial Standard (JIS) (X) 6319-4, and ISO/IEC 15693 standards, Support Reader/Writer (R/W) mode, Active and Passive Peer (P2P) mode.

A simplified block diagram of the module is depicted in the figure below.





3. Deliverables

3.1 Deliverables

The following products and software will be part of the product.

- Module with packaging
- **Evaluation Kits**
- Software utility for integration, performance test.
- Product Datasheet.
- Agency certified pre-tested report with the adapter board.

3.2 Regulatory certifications

The product delivery is a pre-tested module, without the module level certification. For module approval, the platform's antennas are required for the certification.



4. General Specification

4.1 General Specification

Model Name	AP6493		
Product Description	Support WiFi/Bluetooth/NFC functionalities		
Dimension	L x W x H: 12.0 x 12.0 x 1.5 (typical) mm		
WiFi Interface	SDIOV2.0 (4bit/1bit)		
BT Interface	UART/ PCM		
NFC Interface	I2C		
Operating temperature	-30°C to 85°C		
Storage temperature	-40°C to 85°C		
Humidity	Operating Humidity 10% to 95% Non-Condensing		

4.2 Voltages

4.2.1 Absolute Maximum Ratings

Symbol	Description	Min.	Max.	Unit
VBAT	Input supply Voltage	-0.5	6	V
VDDIO	Digital/Bluetooth/SDIO/ I/O Voltage		2.98	V

4.2.2 Recommended Operating Rating

The module requires two power supplies: VBAT and VDDIO.

	Min.	Тур.	Max.	Unit
Operating Temperature	-30	25	85	deg.C
VBAT	3.0	3.6	4.8	V
VDDIO	1.62	1.8	2.9+/-3%	V
VDDSWP_IN ETSI compliant to power class C	1.78	1.88	1.98	V
VDDSWP_IN ETSI compliant to power class B	2.9	3.1	3.3	V



5. WiFi RF Specification

5.1 2.4GHz RF Specification

Conditions: VBAT=3.6V; VDDIO=2.9V; Temp:25°C

Feature	Description			
WLAN Standard	IEEE 802.11b/g/n, WiFi compliant			
Frequency Range	2.400 GHz ~ 2.497 GHz (2.4 GHz ISM Band)			
Number of Channels	2.4GHz: Ch1 ~ Ch14			
Modulation	802.11b: DQPSK, DBPSK, CCK			
Modulation	802.11 g/n : OFDM /64-QAM,16-QAM, QPSK, BPSK			
	802.11b /11Mbps : 16 dBm ± 1.5 dB @ EVM ≤ -9dB			
Output Power	802.11g /54Mbps : 15 dBm ± 1.5 dB @ EVM ≤ -25dB			
	802.11n /65Mbps : 14 dBm ± 1.5 dB @ EVM ≤ -28dB			
	- MCS=0 PER @ -85 dBm, typical			
A 117	- MCS=1 PER @ -84 dBm, typical			
Receive Sensitivity	- MCS=2 PER @ -82 dBm, typical			
(11n,20MHz)	- MCS=3 PER @ -80 dBm, typical			
@10% PER	- MCS=4 PER @ -77 dBm, typical			
@10701 ER	- MCS=5 PER @ -73 dBm, typical			
W.	- MCS=6 PER @ -71 dBm, typical			
₩.	- MCS=7 PER @ -69 dBm, typical			
	- 6Mbps PER @ -86 dBm, typical			
	- 9Mbps PER @ -85 dBm, typical			
	- 12Mbps PER @ -85 dBm, typical			
Receive Sensitivity (11g)	- 18Mbps PER @ -83 dBm, typical			
@10% PER	- 24Mbps PER @ -81 dBm, typical			
	- 36Mbps PER @ -78 dBm, typical			
	- 48Mbps PER @ -73 dBm, typical			
* = =	- 54Mbps PER @ -72 dBm, typical			
	- 1Mbps PER @ -90 dBm, typical			
Receive Sensitivity (11b)	- 2Mbps PER @ -89 dBm, typical			
@8% PER	- 5.5Mbps PER @ -88 dBm, typical			
	- 11Mbps PER @ -85 dBm, typical			
Data Rate	802.11b: 1, 2, 5.5, 11Mbps			
	802.11g: 6, 9, 12, 18, 24, 36, 48, 54Mbps			





Data Rate	802.11n: 6.5, 13, 19.5, 26, 39, 52, 58.5, 65Mbps		
(20MHz ,Long GI,800ns)			
Data Rate	802.11n: 7.2, 14.4, 21.7, 28.9, 43.3, 57.8, 65,72.2Mbps		
(20MHz ,short GI,400ns)			
Maximum Input Laval	802.11b : -10 dBm		
Maximum Input Level	802.11g/n : -20 dBm		
Antenna Reference	Small antennas with 0~2 dBi peak gain		





6. Bluetooth Specification

6.1 Bluetooth Specification

Conditions: VBAT=3.6V; VDDIO=2.9V; Temp:25°C

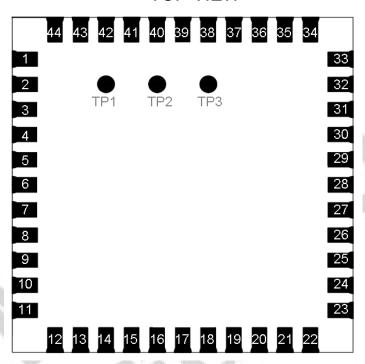
Feature	Description				
General Specification	- 1				
Bluetooth Standard	Bluetooth V4.0	Bluetooth V4.0 of 1, 2 and 3 Mbps.			
Host Interface	UART	UART			
Antenna Reference	Small antennas	s with 0~2 dBi peak	gain		
Frequency Band	2.400 GHz ~ 24	483.5 GHz			
Number of Channels	79 channels	79 channels			
Modulation	FHSS, GFSK,	FHSS, GFSK, DPSK, DQPSK			
RF Specification					
1100.	Min.	Typical.	Max.		
Output Power (Class 1.5)	100	10 dBm			
Output Power (Class 2)	24 B	2 dBm			
Sensitivity @ BER=0.1% for GFSK (1Mbps)	11.	-86 dBm			
Sensitivity @ BER=0.01% for π/4-DQPSK (2Mbps)	1	-86 dBm			
Sensitivity @ BER=0.01% for 8DPSK (3Mbps)		-80 dBm			
	GFSK (1Mbps):-20dBm				
Maximum Input Level	π/4-DQPSK (2	Mbps) :-20dBm			
	8DPSK (3Mbps	8DPSK (3Mbps) :-20dBm			



7. Pin Assignments

7.1 Pin Outline





7.2 Pin Definition

NO	Name	Туре	Description
1	GND	4	Ground connections
2	WL_BT_ANT	I/O	RF I/O port
3	GND	_	Ground connections
4	NC	_	Floating (Don't connected to ground)
5	N_WAKE	I	HOST wake-up NFC device
6	BT_WAKE	I	HOST wake-up Bluetooth device
7	BT_HOST_WAKE	0	Bluetooth device to wake-up HOST
8	N_HOST_WAKE	0	NFC device to wake-up HOST
9	VBAT	Р	Main power voltage source input
10	NC	_	Floating (Don't connected to ground)
11	NC	_	Floating (Don't connected to ground)
12	WL_REG_ON	I	Internal regulators power enable/disable
13	WL_HOST_WAKE	0	WLAN to wake-up HOST



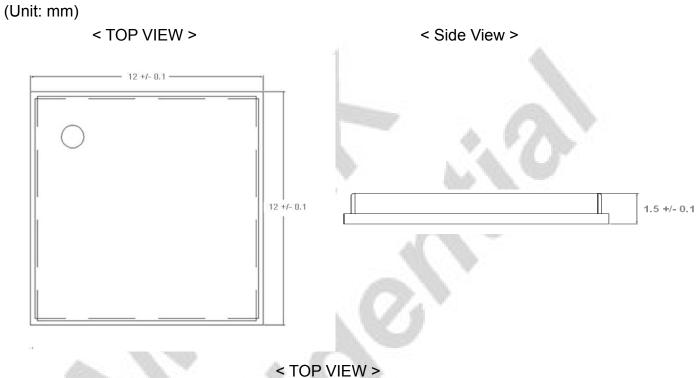


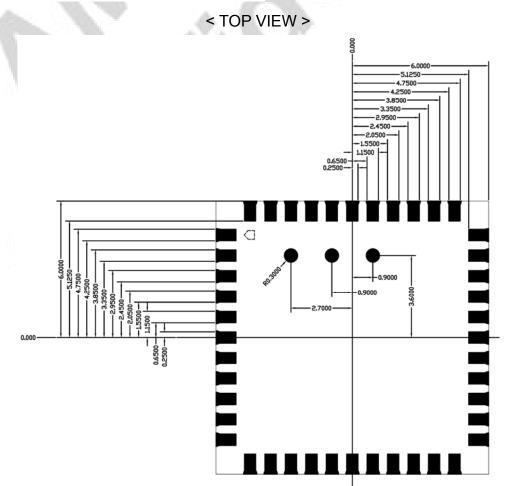
14 SDIO DATA 2	I/O	SDIO data line 2
14 SDIO_DATA_2 15 SDIO_DATA_3	I/O	SDIO data line 3
16 SDIO_DATA_CMD	I/O	SDIO command line
17 SDIO_DATA_CLK	I/O	SDIO clock line
18 SDIO_DATA_0	I/O	SDIO data line 0
19 SDIO_DATA_1	I/O	SDIO data line 1
20 GND	_	Ground connections
21 VIN_LDO_OUT	Р	Internal Buck voltage generation pin
22 VDDIO	Р	I/O Voltage supply input
23 VIN_LDO	Р	Internal Buck voltage generation pin
24 LPO	168	Low power oscillator clock input (32.768KHz)
25 PCM_OUT	I/O	PCM Data output
26 PCM_CLK	I/O	PCM clock
27 PCM_IN	I/O	PCM data input
28 PCM_SYNC	I/O	PCM sync signal
29 VDD_TCXO	Р	1.8V~3.3V supply for internal enable
30 TCXO_IN		26MHz Ref clock input
31 GND	7	Ground connections
32 NC	- 0	Floating (Don't connected to ground)
33 GND	10	Ground connections
34 BT_RST_N	100	Low asserting reset for Bluetooth core
35 N_I2C_SDA	1	BSC Serial Data Line
36 GND	P	Ground connections
37 N_I2C_SCL		BSC Serial Clock
38 N_REG_PU		NFC Internal regulators power enable/disable
39 TX2	0	NFC Tx coil output 2
40 TX1	0	NFC Tx coil output 1
41 UART_RTS_N	0	Bluetooth UART interface
42 UART_TXD	0	Bluetooth UART interface
43 UART_RXD	I	Bluetooth UART interface
44 UART_CTS_N	I	Bluetooth UART interface
45 TP1	I/O	NFC_VDDSWPIO(SWP I/O)
TD0	0	NFC_VDDSWP_OUT(UICC support out)
46 TP2		111 0_1220111 _001(0:00 0appoint oat)



8. Dimensions

8.1 Physical Dimensions



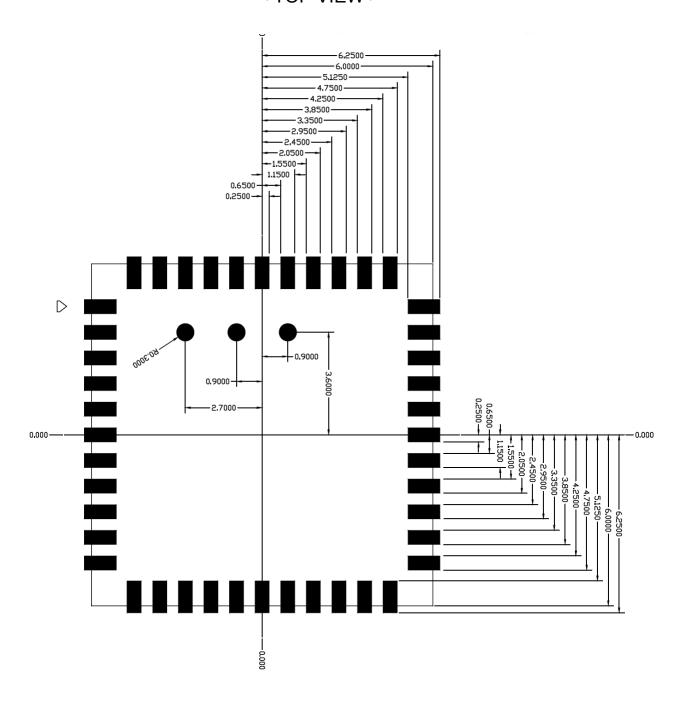




8.2 Layout Recommendation

(Unit: mm)

< TOP VIEW >





External clock reference

External LPO signal characteristics

Parameter	Specification	Units
Nominal input frequency	32.768	kHz
Frequency accuracy	±30	ppm
Duty cycle	30 - 70	%
Input signal amplitude	400 to 1800	mV, p-p
Signal type	Square-wave	
Input impodance	>100k	Ω
Input impedance	<5	pF
Clock jitter (integrated over 300Hz – 15KHz)	<1	Hz
Output high voltage	0.7Vio - Vio	V

External Ref CLK signal characteristics

No	Item	Cumb	Electrical Specification				Damank
No.		Symb.	Min.	Туре	Max.	Units	Remark
1	Nominal Frequency	F0		26.00000		MHz	
2	Mode of Vibration			Funda	mental	•	
3	Frequency Tolerance	ΔF/F0	-10	-	10	ppm	at 25°C±3°C
4	Operating Temperature Range	Topr	-30	-	85	°C	
5	Frequency Stability	TC	-10	-	10	ppm	
6	Storage Temperature	T _{STG}	-55	-	125	$^{\circ}\!\mathbb{C}$	
7	Load capacitance	CL	-	16		pF	
8	Equivalent Series Resistance	ESR	-	-	50	Ω	
9	Drive Level	DL	-	100	200	μW	
10	Insulation Resistance	IR	500	-	-	ΜΩ	At 100V _{DC}
11	Shunt Capacitance	C0	-	-	3	pF	
12	Aging Per Year	Fa	-2	-	2	ppm	First Year

9.1 SDIO Pin Description

The module supports SDIO version 2.0 for 4-bit modes (100 Mbps), and high speed 4-bit (50 MHz clocks - 200 Mbps). It has the ability to stop the SDIO clock and map the interrupt signal into a GPIO pin. This 'out-of-band' interrupt signal notifies the host when the WLAN device wants to turn on the SDIO interface. The ability to force the control of the gated clocks from within the WLAN chip is also provided.



- Function 0 Standard SDIO function (Max BlockSize / ByteCount = 32B)
- Function 1 Backplane Function to access the internal System On Chip (SOC) address space (Max BlockSize / ByteCount = 64B)
- Function 2 WLAN Function for efficient WLAN packet transfer through DMA (Max BlockSize/ByteCount=512B)

SDIO Pin Description

	SD 4-Bit Mode	
DATA0	Data Line 0	
DATA1	Data Line 1 or Interrupt	- 5
DATA2	Data Line 2 or Read Wait	
DATA3	Data Line 3	lb.s
CLK	Clock	- 70
CMD	Command Line	A

10. Host Interface Timing Diagram

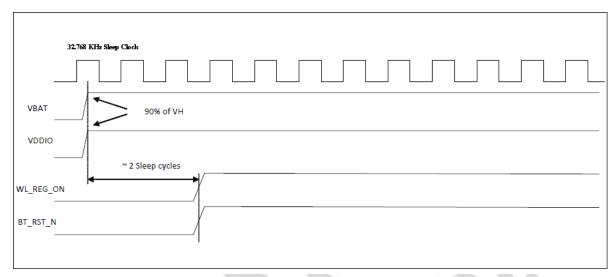
10.1 Power-up Sequence Timing Diagram

The module has signals that allow the host to control power consumption by enabling or disabling the Bluetooth, WLAN and internal regulator blocks. These signals are described below.

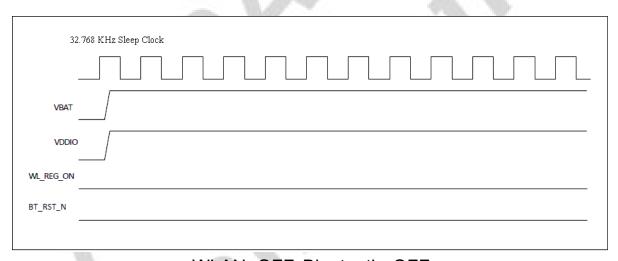
Additionally, diagrams are provided to indicate proper sequencing of the signals for carious operating states. The timing value indicated are minimum required values: longer delays are also acceptable.

- WL_REG_ON: Used by the PMU to power up the WLAN section. When this pin is high, the regulators are enabled and the WLAN section is out of reset. When this pin is low the WLAN section is in reset.
- BT_RST_N: Low asserting reset for Bluetooth only. This pin has no effect on WLAN and does not control any PMU functions. This pin must be driven high or low (not left floating).

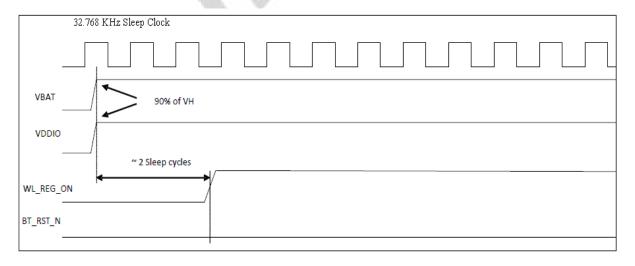




WLAN=ON, Bluetooth=ON

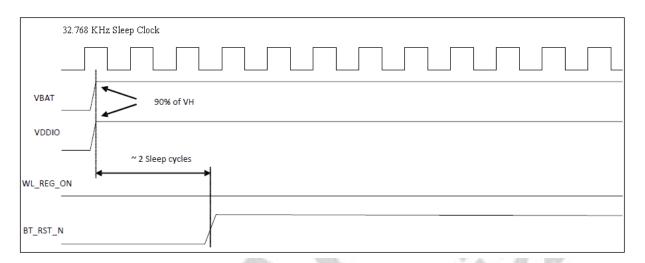


WLAN=OFF, Bluetooth=OFF

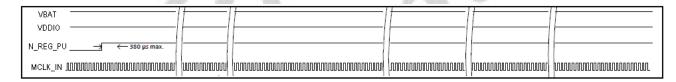


WLAN=ON, Bluetooth=OFF



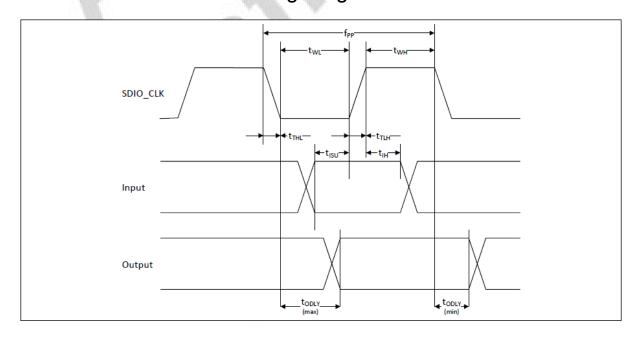


WLAN=OFF, Bluetooth=ON



NFC ON

10.2 SDIO Default Mode Timing Diagram

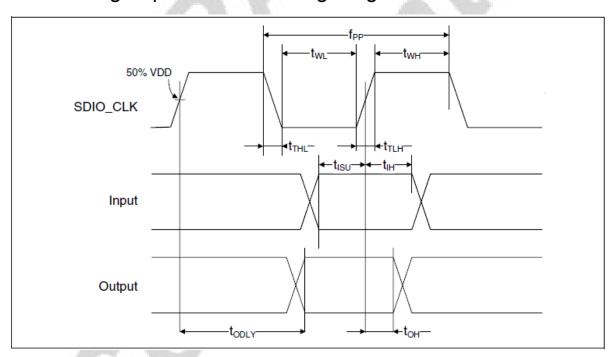




Parameter	Symbol	Minimum	Typical	Maximum	Unit
SDIO CLK (All values are refferred to mini	imum VIH an	d maximum Vi	IL ^b)		
Frequency-Data Transfer mode	fPP	0	-	25	MHz
Frequency-Identification mode	fOD	0	-	400	kHz
Clock low time	tWL	10	-	-	ns
Clock high time	tWH	10	-	-	ns
Clock rise time	tTLH	-	-	10	ns
Clock low time	tTHL	-	-	10	ns
Inputs: CMD, DAT (referenced to CLK)					
Input setup time	tISU	5	-	-	ns
Input hold time	tIH	5	-	-	ns
Outputs: CMD, DAT (referenced to CLK)					
Output delay time - Data Transfer mode	tODLY	0	-	14	ns
Output delay time - Identification mode	tODLY	0	-	50	ns

a. Timing is based on CL ≤ 40pF load on CMD and Data.

10.3 SDIO High Speed Mode Timing Diagram



Parameter	Symbol	Minimum	Typical	Maximum	Unit
SDIO CLK (All values are refferred to mini	mum VIH and	d maximum VI	L ^b)		
Frequency-Data Transfer mode	fPP	0	-	50	MHz
Frequency-Identification mode	fOD	0	-	400	kHz
Clock low time	tWL	7	-	-	ns
Clock high time	tWH	7	-	-	ns
Clock rise time	tTLH	-	-	3	ns
Clock low time	tTHL	-	-	3	ns
Inputs: CMD, DAT (referenced to CLK)					
Input setup time	tISU	6	-	-	ns
Input hold time	tIH	2	-	-	ns
Outputs: CMD, DAT (referenced to CLK)					
Output delay time - Data Transfer mode	tODLY	-	-	14	ns
Output hold time	tOH	2.5	-	-	ns
Total system capacitance (each line)	CL	-	-	40	pF

a. Timing is based on CL \leq 40pF load on CMD and Data.

b. min(Vih) = 0.7 x VDDIO and max(ViI) = 0.2 x VDDIO.

b. $min(Vih) = 0.7 \times VDDIO$ and $max(Vil) = 0.2 \times VDDIO$.

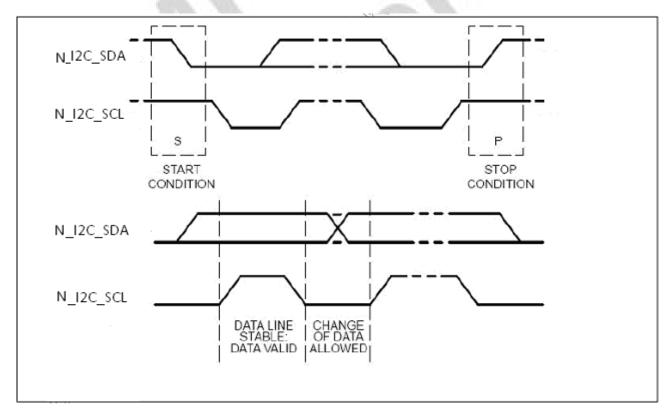


10.4 BSC (I2C-Compatible)

Following are the main features of the BSC host interface:

- Slave mode
- Low-speed mode (100 kbps), fast mode (400 kbps), and high-speed mode (3.4 Mbps) upported. Due topractical constraints imposed by parasitic capacitance and pull-up resistor values, especially in a multidrop system, recommend that this be limited to 1.7 Mbps.
- 7-bit or 10-bit addressing mode; default boot-up of fixed 10-bit address (0x1FA), thereafter configurable to 7-bit or 10-bit addresses
- Dedicated TX and RX FIFOs, 272 bytes each.
- Digital deglitching filter implemented. Uses simple majority of 3 and will filter spikes up to 42 ns.
- High-speed reference not required for operation. (Certain accesses in sleep mode will initiate the wakeup function.)

The BSC timing waveform is shown in

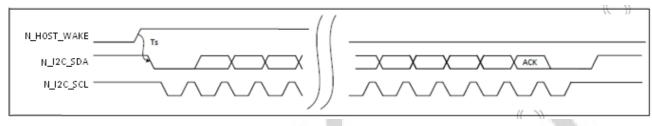


BSC Timing Waveform





NFC_HOST_WAKE is an output signal from the BCM20793S to the host that it wishes to communicate. The timing diagram shows NFC_HOST_WAKE as active high. The NFC_HOST_WAKE signal stays high until after the first byte has been read by the host.



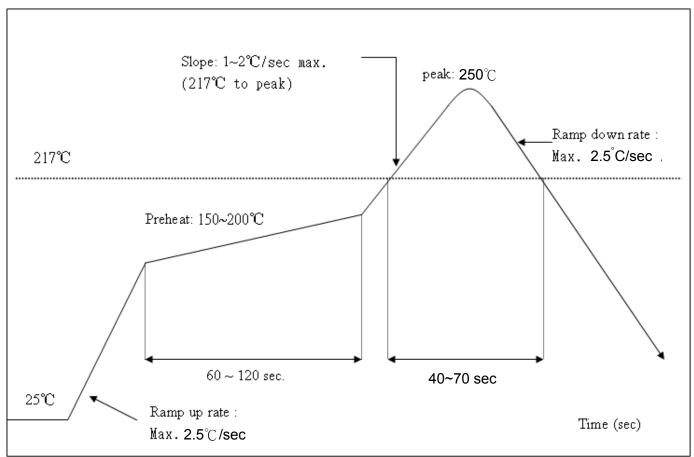
N_HOST_WAKE Timing Waveform



11. Recommended Reflow Profile

Referred to IPC/JEDEC standard.

Peak Temperature: <250°C Number of Times : ≤2 times





12. Package Information

12.1Label

Label A→ Anti-static and humidity notice



Label B→ MSL caution / Storage Condition

	Caution This bag contains MOISTURE-SENSITIVE DEVICES Hard, see adjacen bar code label
1.	Calculated shelf life in sealed bag: 12 months at <40°C and <90% relative humidity (RH)
2.	Peak package body temperature:*C*blank, see adjacent bar code label
3.	After bag is opened, devices that will be subjected to reflow solder or other high temperature process must be
	a) Mounted within: hours of factory conditions solution 1 thank, see adjacent bar code label solution hours of factory conditions solution hou
	b) Stored per J-STD-033
4.	Devices require bake, before mounting, if:
	a) Humidity Indicator Card reads >10% for level 2a - 5a devices or >60% for level 2 devices when read at $23 \pm 5^{\circ}$ C
	b) 3a or 3b are not met
5.	If baking is required, refer to IPC/JEDEC J-STD-033 for bake procedure
Ba	ag Seal Date:
	Note: Level and body temperature defined by IPC/JEDEC J-STD-020

Label C→ Inner box label.

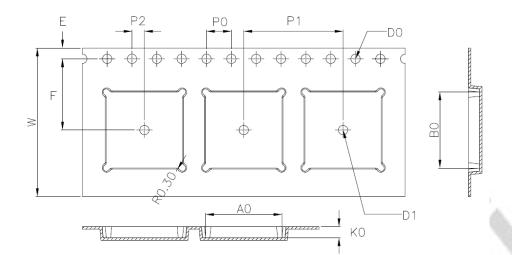
Model: P/N: 99P-W01-0048R Qty: Date Code :

Label D→ Carton box label .



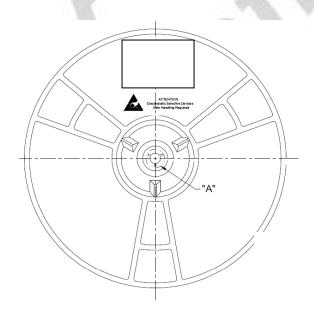


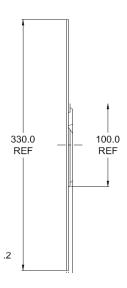
12.2 Dimension



W	24.00±0.30
Α0	12.30±0.10
ВО	12.30±0.10
K0	1.80±0.10
Ε	1.75±0.10
F	11.50±0.10
P0	4.00±0.10
P1	16.00±0.10
P2	2.00±0.10
D0	1.50 +0.10
D1	Ø1.50MIN

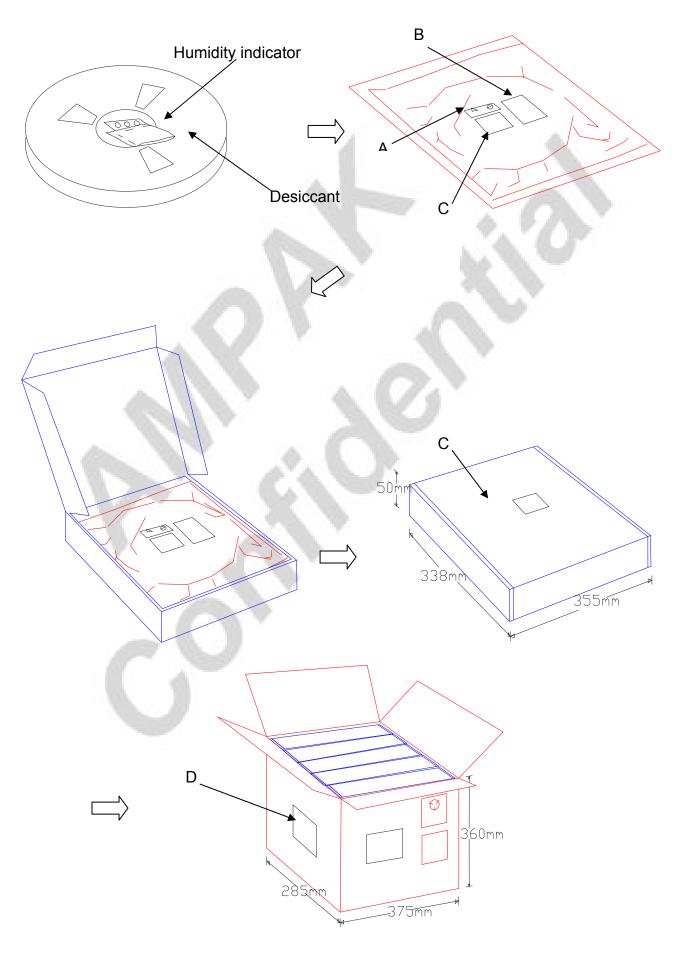
- 1. 10 sprocket hole pitch cumulative tolerance ± 0.20 .
- 2. Carrier camber is within 1 mm in 250 mm.
- 3. Material: Black Conductive Polystyrene Alloy.
- 4. All dimensions meet EIA-481-D requirements.
- 5. Thickness: 0.30±0.05mm.
- 6. Packing length per 22" reel: 98.5 Meters.(1:3)
- 7. Component load per 13" reel: 1500 pcs.













12.3 MSL Level / Storage Condition

LEVEL
Caution 4
This bag contains 4
MOISTURE-SENSITIVE DEVICES
Do not open except under controlled conditions
1. Calculated shelf life in sealed bag: 12 months at< 40° and
< 90% relative humidity(RH)
225°C 240°C 250°C 260°C
2. Peak package body temperature:
 After bag is opened, devices that will be subjected to reflow solder or other high temperature process must a) Mounted within: 48 hours of factory conditions <30°C/60% RH, OR b) Stored at <10% RH
 Devices require bake, before mounting, if: a)Humidity Indicator Card is>10%when read at 23±5℃ b)3a or 3b not met
5. If baking is required, devices may be baked for 24 hours at 125±5℃
Note: If device containers cannot be subjected to high temperature or shorter bake times are desired,
reference IPC/JEDEC J-STD-033 for bake procedure
Bag Seal Date: See-SEAL DATELABEL
Note:Level and body temperature defined by IPC/JEDED J-STD-020

※NOTE: Accumulated baking time should not exceed 96hrs